RF2314

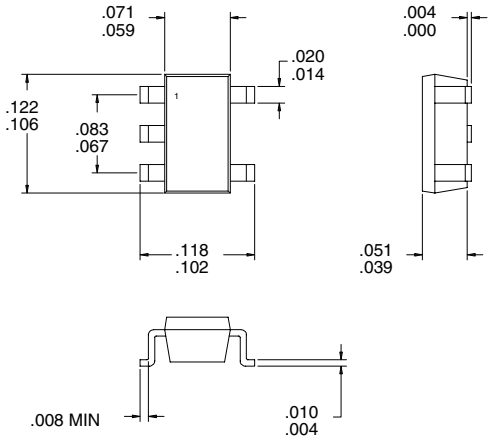
GENERAL PURPOSE LOW NOISE AMPLIFIER

Typical Applications

- Broadband Gain Blocks
- Final PA for Low-Power Applications
- IF or RF Buffer Amplifiers
- Driver Stage for Power Amplifiers
- Oscillator Loop Amplifiers

Product Description

The RF2314 is a general purpose, low-cost, high performance amplifier designed for operation from a 2.7V to 6V supply with low current consumption. The circuit configuration with resistive feedback allows for broadband cascadable amplification. Feedback with capacitive compensation extends the bandwidth of the amplifier, and is designed for optimized noise figure. The device is unconditionally stable and internally matched to 50Ω. **No external components** are required. The RF2314 is available in a very small industry-standard SOT-23 5-lead surface mount package, enabling compact designs which conserve board space.



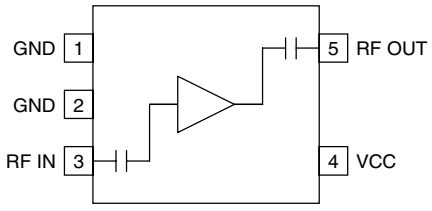
Package Style: SOT-23-5

Optimum Technology Matching® Applied

- ☐ Si BJT
- ☑ GaAs HBT
- ☐ GaAs MESFET
- ☐ Si Bi-CMOS
- ☐ SiGe HBT
- ☐ Si CMOS

Features

- 150MHz to 2500MHz Operation
- 2.7V to 6.0V Single Supply
- +18dBm Output IP_3 at 5V
- 14dB Gain at 900MHz
- 8.6dB Gain at 1900MHz
- Low Current Consumption of 5mA at 3V



Functional Block Diagram

Ordering Information

RF2314	General Purpose Low Noise Amplifier
RF2314 PCBA	Fully Assembled Evaluation Board

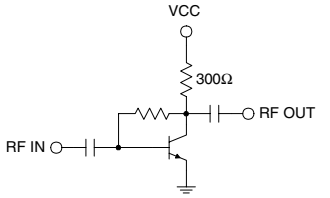
RF Micro Devices, Inc.
7625 Thorndike Road
Greensboro, NC 27409, USA
Tel (336) 664 1233
Fax (336) 664 0454
http://www.rfmd.com

Absolute Maximum Ratings

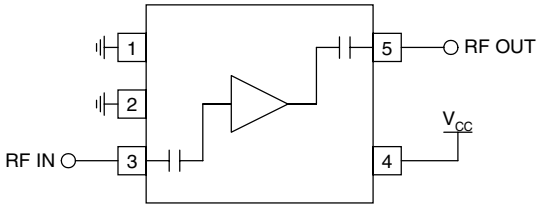
Parameter	Rating	Unit
Supply Voltage	8.0	V
Supply Current	32	mA
Operating Ambient Temperature	-40 to +85	°C
Storage Temperature	-40 to +150	°C

Caution! ESD sensitive device.

Parameter	Specification			Unit	Condition
	Min.	Typ.	Max.		
Overall					T=27 °C, V_{CC}=3.0V, Freq=900MHz
Frequency Range		150 to >2500		MHz	NOTE: Lower frequencies can be obtained with inductive coupling.
3.0V Performance					T=27 °C, V_{CC}=3.0V, Freq=900MHz
Gain		12.9		dB	
		16.6		dB	Freq=150MHz
		7.9		dB	Freq=1900MHz
Noise Figure		1.4		dB	
Output IP3		+9.0		dBm	
Output P_{1dB}		-1.0		dBm	
Input Return Loss		10		dB	
Output Return Loss		17		dB	
Isolation		20		dB	
5.0V Performance					T=27 °C, V_{CC}=5.0V, Freq=900MHz
Gain		14.2		dB	
		19.1		dB	Freq=150MHz
		8.6		dB	Freq=1900MHz
Noise Figure		1.5		dB	
Output IP3		+18.0		dBm	
Output P_{1dB}		+8.0		dBm	
Input Return Loss		13		dB	
Output Return Loss		28		dB	
Isolation		20		dB	
Power Supply					
Operating Voltage		2.7 to 6.0		V	
Operating Current		5.7		mA	V_{CC}=3.0V
		12.5		mA	V_{CC}=5.0V

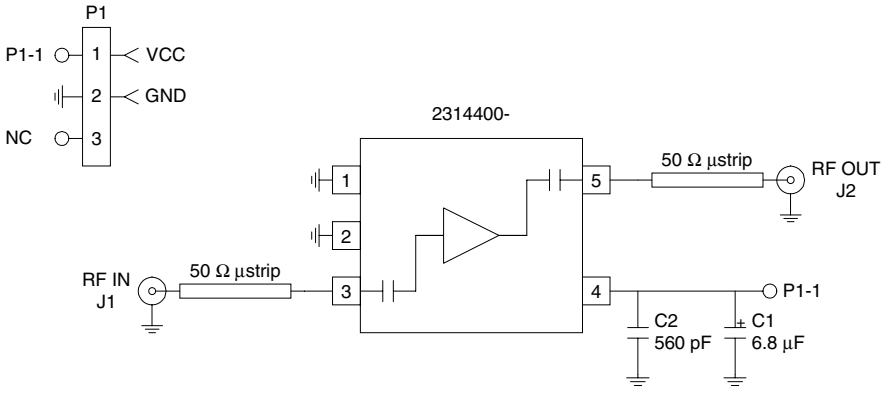
Pin	Function	Description	Interface Schematic
1	GND	Ground connection. Keep traces physically short and connect immediately to ground plane for best performance.	
2	GND	Same as pin 1.	
3	RF IN	RF input pin. This pin is internally DC blocked and thus does not require an external blocking capacitor. The input impedance of this pin is internally matched to 50Ω using resistive feedback.	
4	VCC	Supply connection. Generally, there is no need for an external bypass capacitor.	See pin 3 schematic.
5	RF OUT	RF output pin. The output impedance of this pin is internally matched to 50Ω using resistive feedback.	See pin 3 schematic.

Application Schematic



Evaluation Board Schematic

(Download Bill of Materials from www.rfmd.com.)



Evaluation Board Layout
Board Size 1.0” x 1.0”